# NSN 5961-01-088-6987

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Inclosure Material:

Metal

**Overall Length:** 

0.643 inches

# Terminal Length:

0.590 inches

#### **Overall Height:**

0.085 inches

#### **Overall Width:**

0.505 inches

#### Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open

#### **Current Rating Per Characteristic:**

8.00 amperes source cutoff current and 120.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

2.2 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

3 uninsulated wire lead

# **Specification Data:**

80131-release6403 professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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